MM60FU60BC

600V 60A FRED

April 2018

RoHS Compliant

PRODUCT FEATURES

☐Ultrafast Recovery Time

☐Low Recovery Loss

☐Soft Reverse Recovery Characteristics

☐Low Leakage Current

☐Low Forward Voltage

☐High Surge Current Capability

APPLICATIONS

☐Freewheeling, Snubber, Clamp

☐Inversion Welder

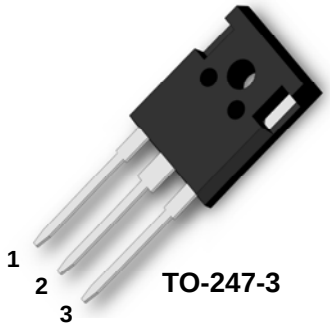
☐PFC

☐Plating Power Supply

☐Ultrasonic Cleaner and Welder

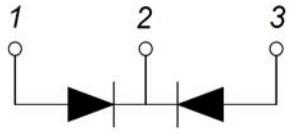
☐Converter & Chopper

☐UPS



DESCRIPTION

FRED from MacMic utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.



ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise specified)

Symbol	Parameter/Test Conditions		Values	Unit
V_R	Maximum D.C. Reverse Voltage		600	V
V_{RRM}	Maximum Repetitive Reverse Voltage			
$I_{F(AV)}$	Average Forward Current	T_C=120℃, Per Diode	30	A
		T_C=120℃, Per Package	60	
$I_{F(RMS)}$	RMS Forward Current	T_C=120℃, Per Diode	42	
I_{FSM}	Non Repetitive Surge Forward Current	T_J=25℃,t=10ms, 50Hz, Sine	260	
P_D	Power Dissipation		187	W
T_J	Junction Temperature		-55 to +175	℃
T_{STG}	Storage Temperature Range		-55 to +150	℃
Torque	To Heat Sink	Recommended（M3）	1.1	Nm
R_{thJC}	Junction to Case Thermal Resistance(Per Diode)		0.8	℃ /W
Weight			6	g

ELECTRICAL CHARACTERISTICS (T_C=25°C unless otherwise specified)

Symbol	Parameter/Test Conditions		Min.	Typ.	Max.	Unit
I_{RM}	Maximum Reverse Leakage Current	V_R =600V			10	μA
		V_R =600V, T_J = 150℃			1	mA
V_F	Forward Voltage	I_F=30A		2	2.4	V
		I_F=30A,T_J=150℃		1.6		
trr	Reverse Recovery Time (I_F = 1A, dI_F/dt = -200A/μs, V_R = 30V)			20	25	ns
trr	Reverse Recovery Time (I_F = 0.5A, I_R=1A, I_{RR} = 0.25A)			30	40	ns

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ELECTRICAL CHARACTERISTICS *(T_C =25°C unless otherwise specified)*

Symbol	Parameter/Test Conditions		Min.	Typ.	Max.	Unit
trr	Reverse Recovery Time	I_F =30A,V_R =300V, dI_F/dt = -200A/μs		35		ns
I_{RRM}	Maximum Reverse Recovery Current			3		A
Q_{RR}	Reverse Recovery Charge			128		nC
trr	Reverse Recovery Time	I_F =30A,V_R =300V, dI_F/dt = -200A/μs ,T_J=150℃		145		ns
I_{RRM}	Maximum Reverse Recovery Current			6.9		A
Q_{RR}	Reverse Recovery Charge			600		nC

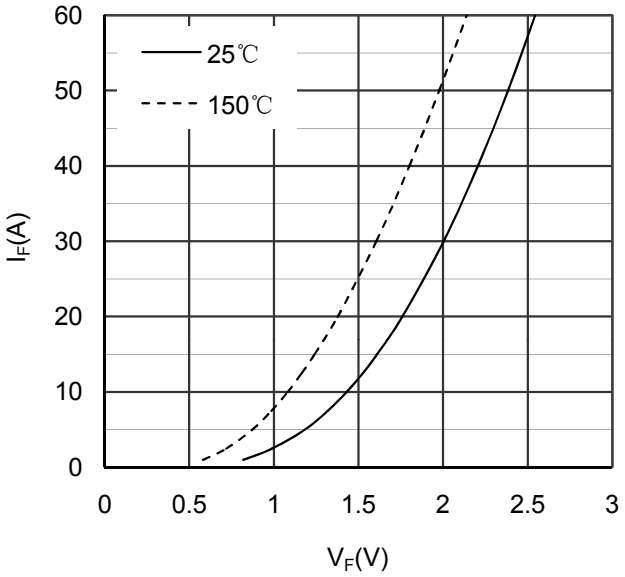


Figure 1. Forward Voltage Drop vs Forward Current

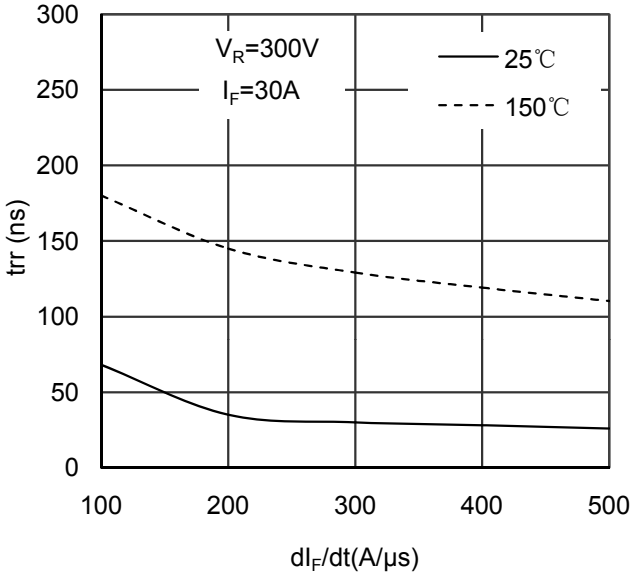


Figure 2. Reverse Recovery Time vs dI_F/dt

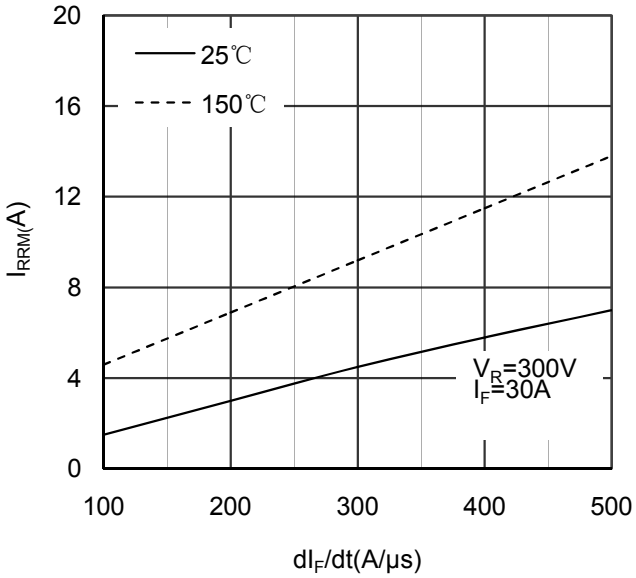


Figure 3. Reverse Recovery Current vs dI_F/dt

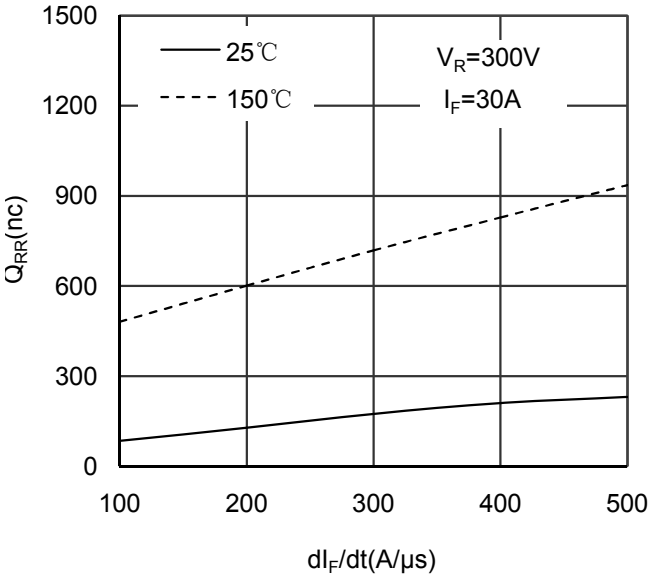


Figure 4. Reverse Recovery Charge vs dI_F/dt

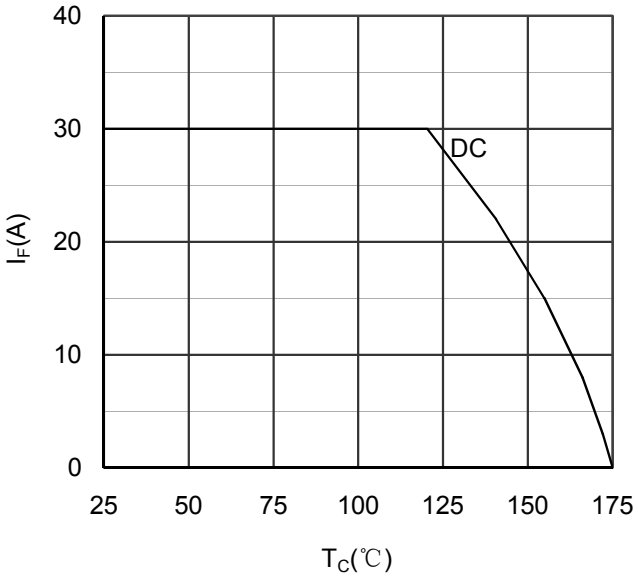


Figure 5.Forward current vs Case temperature

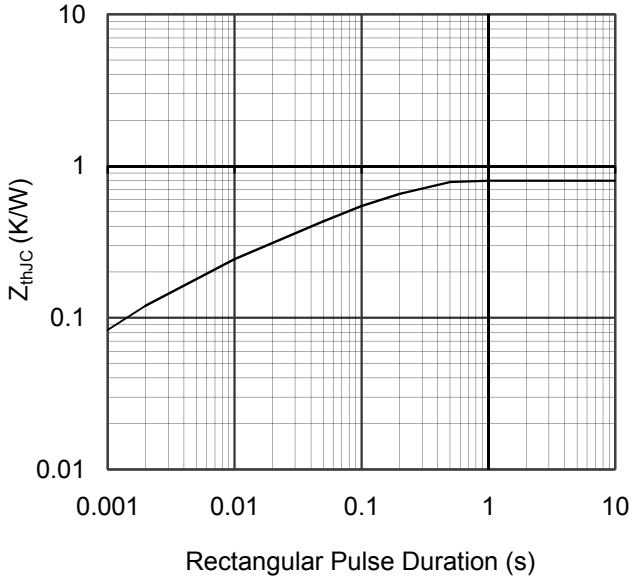


Figure 6.Transient Thermal Impedance

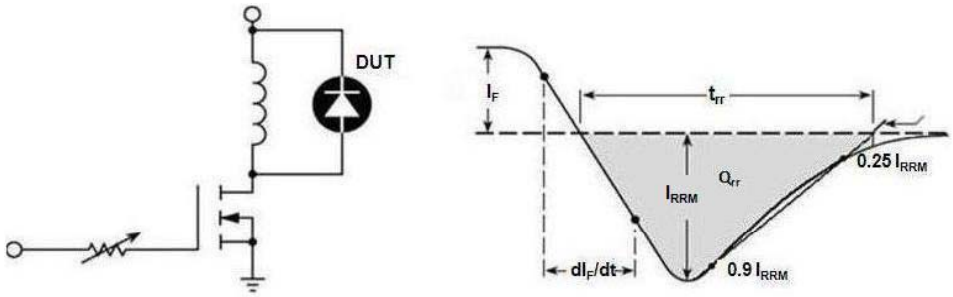
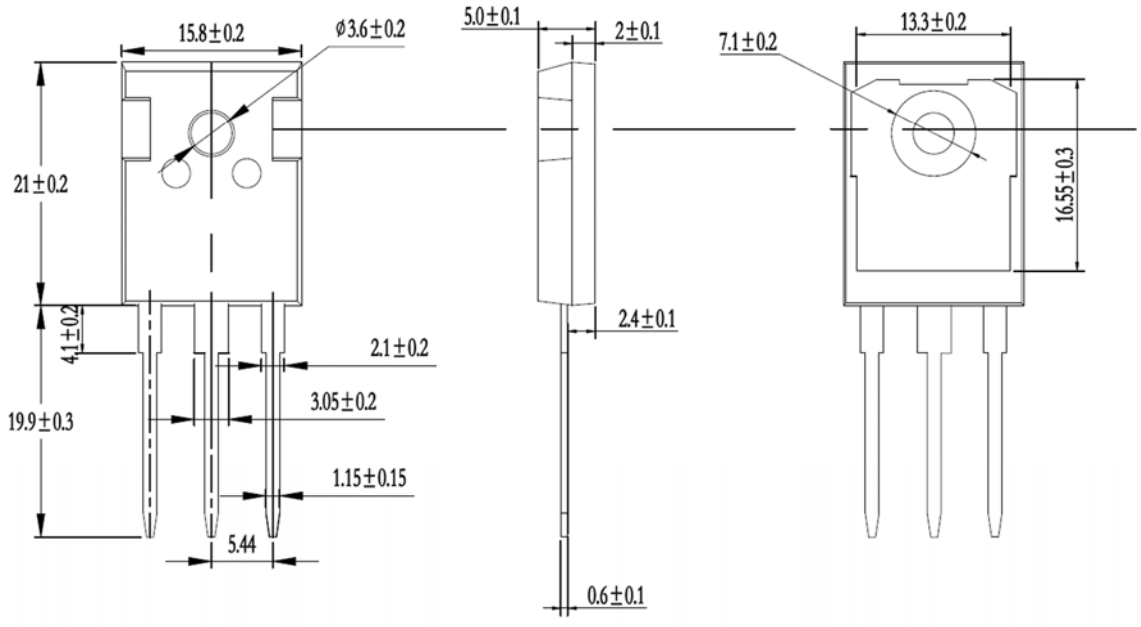


Figure 7. Diode Reverse Recovery Test Circuit and Waveform



Dimensions in (mm)

Figure 8. Package Outline